

SANYO Semiconductors **DATA SHEET**

LA4227

Monolithic Linear IC

Audio Output for Radio Cassette Recorders 3W × 2ch Power Amplifier

Overview

LA4227 is a 3W 2-channel power amplifier.

This IC requires few external components and is ideal for power amplifier used for radio cassette players/recorders.

Functions

- $3W \times 2$ channel ($V_{CC} = 9V$, $R_L = 3\Omega$)
- Standby switch on chip
- Thermal shutdown protector on chip

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max	Rg = 0 (No signal)	20	٧
Allowable power dissipation	Pd max	Arbitrarily large heat sink	4.0	W
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-55 to +150	°C

Operating Conditions at Ta=25°C

Parameter	Symbol	Conditions	Ratings	unit
Recommended supply voltage	Vcc /		9	V
Operating voltage range	V _{CC} op	Not exceeding the maximum ratings	4.2 to 18	V
Operating load resistance range	R _L op		3 to 8	Ω
		Bridge	8	Ω

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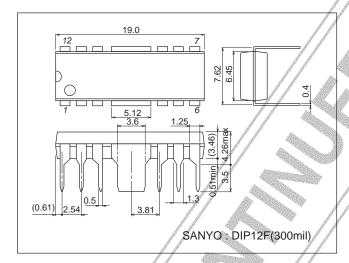
LA4227

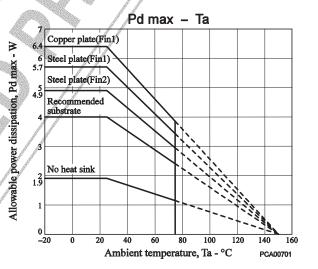
$\textbf{Electrical Characteristics} \ at \ Ta=25^{\circ}C, \ V_{CC}=9V, \ R_{L}=4\Omega, \ f=1kHz, \ Rg=600\Omega, \ R_{NF}=43\Omega$

Parameter	Symbol	Conditions	Ratings			Llait
			min	typ	max	Unit
Quiescent current	Icco	Rg = 0	10	20	40	mA
Voltage gain	VG	$V_O = 0$ dBm	43.0	45.0	47.0	dB
Voltage gain difference	ΔVG				2.0	dB
Total harmonic distortion	THD	$P_O = 0.25W (V_O = 1V)$		0.2	1.0	%
Output power	P _O 1	THD = 10%	2.0	2.5		W
	P _O 2	$R_L = 3\Omega$, THD = 10%		3.0	The state of the s	W
	P _O 3	Bridge, $R_L = 8\Omega$, THD = 10%	1	(4.7)	The state of the s	W
Output noise voltage	V _{NO1}	Rg = 0, DIN AUDIO		0.3	1.0	m۷
	V _{NO2}	Rg = 10kΩ, DIN AUDIO		0.4	2.0	mV
Channel separation	Chsep	$V_O = 0$ dBm, Rg = 10 k Ω	45	55		dB
Ripple rejection	SVRR	$Vr = 150mV$, $Rg = 0$, $f_r = 100Hz$, DIN AUDIO	40	52		dB
Standby current	Ist	1	/		// 10	μΑ
Input resistance	Ri		21	30		kΩ

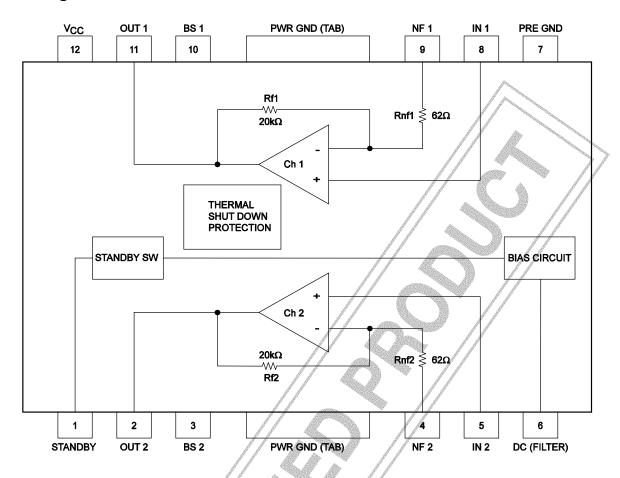
Package Dimensions

unit : mm 3022B

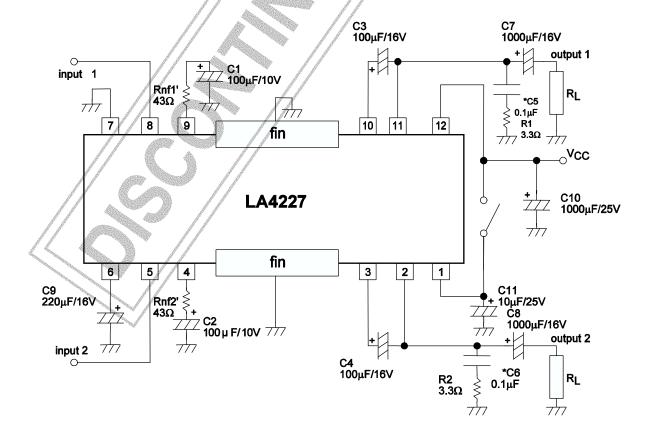




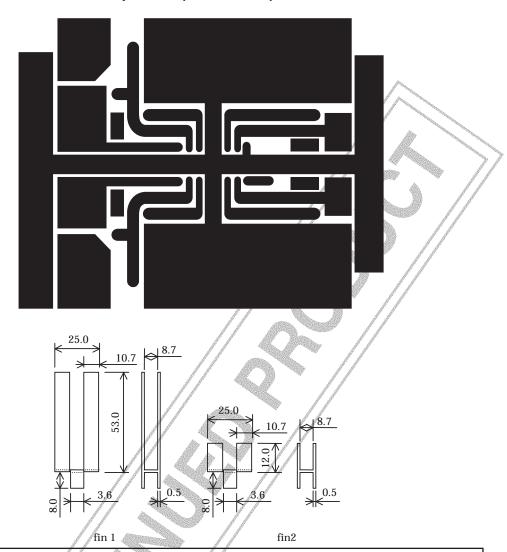
Block Diagram



Application Circuit Example



Recommended board Cu-foiled pattern (Actual size)



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